



MJ2501
MJ3001

COMPLEMENTARY SILICON POWER DARLINGTON TRANSISTORS

- STMicroelectronics PREFERRED SALESTYPES
- COMPLEMENTARY PNP - NPN DEVICES

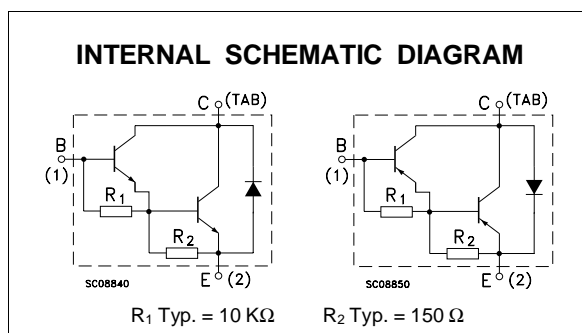
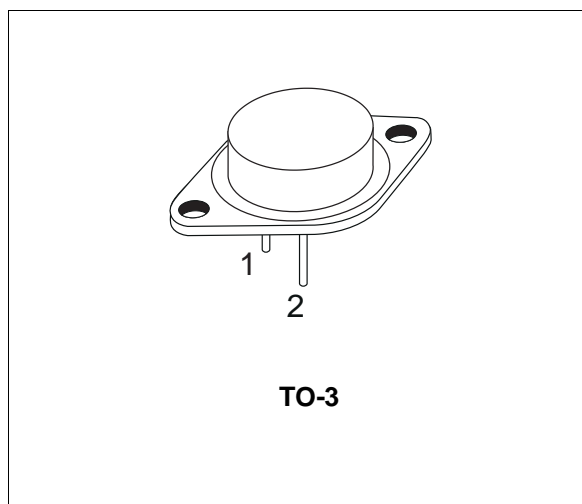
APPLICATION

- AUDIO POWER AMPLIFIER
- DC-AC CONVERTER
- EASY DRIVER FOR LOW VOLTAGE DC MOTOR
- GENERAL POWER SWITCHING

DESCRIPTION

The MJ2501 is a Silicon Epitaxial-Base PNP power transistors in monolithic Darlington configuration, mounted in Jedec TO-3 metal case. It is intended for use in power linear and switching applications.

The complementary NPN type is the MJ3001.



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter		Value	Unit
		PNP	MJ2501	
		NPN	MJ3001	
V _{CBO}	Collector-base Voltage (I _E = 0)		80	V
V _{CEO}	Collector-emitter Voltage (I _B = 0)		80	V
V _{EBO}	Emitter-base Voltage (I _C = 0)		5	V
I _C	Collector Current		10	A
I _B	Base Current		0.2	A
P _{tot}	Total Dissipation at T _c ≤ 25 °C		150	W
T _{stg}	Storage Temperature		-65 to 200	°C
T _j	Max. Operating Junction Temperature		200	°C

For PNP types voltage and current values are negative.

THERMAL DATA

$R_{thj-case}$	Thermal Resistance Junction-case	Max	1.17	°C/W
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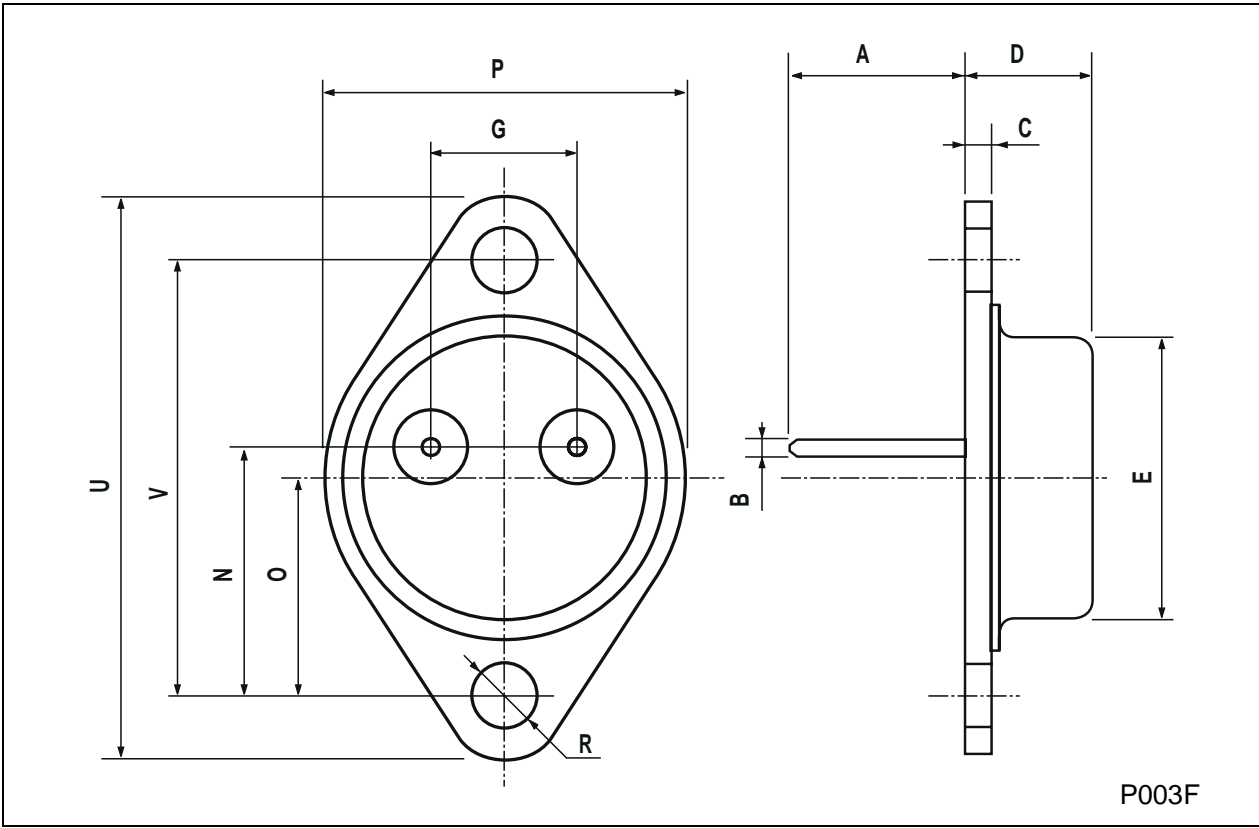
ELECTRICAL CHARACTERISTICS ($T_{case} = 25\text{ °C}$ unless otherwise specified)

Symbol	Parameter	Test Conditions		Min.	Typ.	Max.	Unit
I_{CER}	Collector Cut-off Current ($R_{BE} = 1\text{ K}\Omega$)	$V_{CE} = 80\text{ V}$				1	mA
		$T_{case} = 150\text{ °C}$ $V_{CE} = 80\text{ V}$				5	mA
I_{CEO}	Collector Cut-off Current ($I_B = 0$)	$V_{CE} = 30\text{ V}$ $V_{CE} = 40\text{ V}$				1 1	mA mA
I_{EBO}	Emitter Cut-off Current ($I_C = 0$)	$V_{EB} = 5\text{ V}$				2	mA
$V_{CEO(sus)}^*$	Collector-Emitter Sustaining Voltage ($I_B = 0$)	$I_C = 100\text{ mA}$		80			V
$V_{CE(sat)}^*$	Collector-emitter Saturation Voltage	$I_C = 5\text{ A}$ $I_B = 20\text{ mA}$				2	V
		$I_C = 10\text{ A}$ $I_B = 50\text{ mA}$				4	V
V_{BE}^*	Base-emitter Voltage	$I_C = 5\text{ A}$ $V_{CE} = 3\text{ V}$				3	V
h_{FE}^*	DC Current Gain	$I_C = 5\text{ A}$ $V_{CE} = 3\text{ V}$		1000			

* Pulsed: Pulse duration = 300 μ s, duty cycle 1.5 %
For PNP types voltage and current values are negative.

TO-3 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	11.00		13.10	0.433		0.516
B	0.97		1.15	0.038		0.045
C	1.50		1.65	0.059		0.065
D	8.32		8.92	0.327		0.351
E	19.00		20.00	0.748		0.787
G	10.70		11.10	0.421		0.437
N	16.50		17.20	0.649		0.677
P	25.00		26.00	0.984		1.023
R	4.00		4.09	0.157		0.161
U	38.50		39.30	1.515		1.547
V	30.00		30.30	1.187		1.193



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